

**Erratum: Mie Resonances, Infrared Emission, and the Band Gap of InN**  
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On the page 117407-3, left column, the text in the last paragraph should be written as follows.

“Such a small  $L_m$  value means that the respective clusters are elongated along the electric field vector of the incident light, like the interface indium inclusions. In this case, the depolarization is small, and the resonance energy is the lowest among those possible [16]. This type of clusters determines the effective absorption edge in InN. The resonances of the clusters with  $L_m \geq 0.33$  are higher in energy than the absorption edge in InN, so the prolate intercolumn inclusions do not affect the effective band edge.”

This correction affects the speculation concerning the type of the In clusters involved, but changes none of our main results.

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